

Analog Semiconductor IC

VRD Series

High speed, Low dropout, ±1% High output accuracy CMOS Voltage Regulator with Dual output

(IMPORTANT: Please check the last page for Genuine Product Labeling)

Rev. E19-01

Website: www.anasemi.com
Tel: +852-3590-8442
Email: sales@anasemi.com





Products Data Sheet

Analog Semiconductor IC

High speed, Low dropout, ±1% High output accuracy Dual CMOS Voltage Regulator

VRD Series

GENERAL DESCRIPTIONS

The VRD series are dual positive voltage regulators with high speed, low voltage dropout and high accuracy output achieved by low current consumption. Because each regulator is completely separated, the crosstalk between each regulator can be reduced. The output voltage is guaranteed within ±1% within the given temperature range by Vref controlling the temperature characteristic. It corresponds to the low ESR capacitor as an output stabilization capacitor. The charged ESR capacitor can be discharged with an internal switch by making the CE=Vss, as a result the Vout quickly returns to the Vss level. To make the current capacity of the output transistor not exceeded, the over-current protection circuit is built in.



FEATURES

• Output voltage range ················ 0.8V~5.0V (selectable with a step of 0.05V)

Operating voltage range ······················· 1.6V~6.0V

High accuracy output voltage ····· ±1% (Vout=1.95V~ 5.0V) / ±20mV (Vout=0.8V~1.9V)

Maximum output current ------- 250mA / Channel

● Low current consumption · Typ. 25µA / Channel

High ripple rejection ······ Typ. 75dB at 1KHz

Low ESR capacitor · · · · · · 1.0 μF ceramic capacitor

• Operating temperature range ····· –40°C ~ +85°C

Built-in over-current protector Limit current : 300mA

CL high-speed auto-discharge

• Built-in On/Off circuit

• Small package · · · · · SOT-26 (2.9×2.8×1.1mm), LLP-6 (1.8×2.0×0.6mm), SON-6 (1.8×2.0×0.6mm)

APPLICATIONS

Battery powered devices

Cellular phone

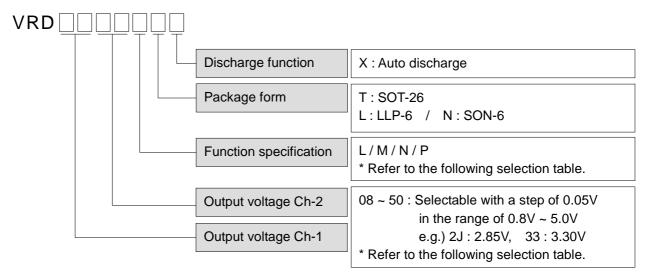
Digital / Video cameras

Portable games

Handheld instruments

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PRODUCTS NUMBERING GUIDE



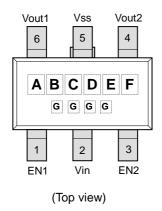
• Function specification selection table

Symbol	VR1	VR2	Function Specification
L	±20mv	±20mv	Vout1=0.80V~1.9V / Vout2=0.80V~1.9V
M	±20mv	±1%	Vout1=0.80V~1.9V / Vout2=1.95V~5.0V
N	±1%	±20mv	Vout1=1.95V~5.0V / Vout2=0.80V~1.9V
Р	±1%	±1%	Vout1=1.95V~5.0V / Vout2=1.95V~5.0V

• Output voltage selection table

Symbol	Voltage								
		1A	1.05	2A	2.05	3A	3.05	4A	4.05
		11	1.10	21	2.10	31	3.10	41	4.10
		1B	1.15	2B	2.15	3B	3.15	4B	4.15
		12	1.20	22	2.20	32	3.20	42	4.20
		1C	1.25	2C	2.25	3C	3.25	4C	4.25
		13	1.30	23	2.30	33	3.30	43	4.30
		1D	1.35	2D	2.35	3D	3.35	4D	4.35
		14	1.40	24	2.40	34	3.40	44	4.40
		1E	1.45	2E	2.45	3E	3.45	4E	4.45
		15	1.50	25	2.50	35	3.50	45	4.50
		1F	1.55	2F	2.55	3F	3.55	4F	4.55
		16	1.60	26	2.60	36	3.60	46	4.60
		1G	1.65	2G	2.65	3G	3.65	4G	4.65
		17	1.70	27	2.70	37	3.70	47	4.70
		1H	1.75	2H	2.75	3H	3.75	4H	4.75
08	0.80	18	1.80	28	2.80	38	3.80	48	4.80
0J	0.85	1J	1.85	2J	2.85	3J	3.85	4J	4.85
09	0.90	19	1.90	29	2.90	39	3.90	49	4.90
0K	0.95	1K	1.95	2K	2.95	3K	3.95	4K	4.95
10	1.00	20	2.00	30	3.00	40	4.00	50	5.00

PIN CONFIGURATION / MARKING SPECIFICATION (SOT-26)



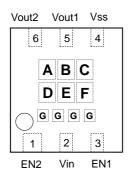
Pin Configuration

No.	Symbol	Descriptions			
1	EN1	1-Channel enable			
2	VIN	Voltage input			
3	EN2	2-Channel enable			
4	Vout2	2-Channel output			
5	Vss	Power ground			
6	Vout1	1-Channel output			

Marking Specification

Co	de	Mark	Contents			
	١	D	Products series name			
В	С	08~50	1-Ch output voltage			
D	E	08~50	2-Ch output voltage			
F	•	Х	Discharge function			
C	}	Internal rule	Lot number			

PIN CONFIGURATION / MARKING SPECIFICATION (LLP-6)



(Top view)

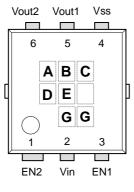
Pin Configuration

No.	Symbol	Descriptions
1	EN2	2-Channel enable
2	VIN	Voltage input
3	EN1	1-Channel enable
4	Vss	Power ground
5	Vout1	1-Channel output
6	Vout2	2-Channel output

Marking Specification

Code	Mark	Contents				
Α	D	Products series name				
ВС	08~50	1-Ch output voltage				
DE	08~50	2-Ch output voltage				
F	Х	Discharge function				
G	Internal rule	Lot number				

PIN CONFIGURATION / MARKING SPECIFICATION (SON-6)



(Top view)

Pin Configuration

No.	Symbol	Descriptions
1	EN2	2-Channel enable
2	VIN	Voltage input
3	EN1	1-Channel enable
4	Vss	Power ground
5	Vout1	1-Channel output
6	Vout2	2-Channel output

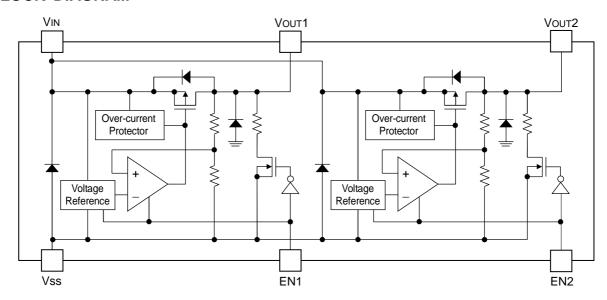
Marking Specification

_							
	Code	Mark	Contents				
_	Α	D	Products series name				
	ВС	08~50	1-Ch output voltage				
	DE	08~50	2-Ch output voltage				
_	F	Х	Discharge function				
	G	Internal rule	Lot number				

High speed, Low dropout, ±1% High output accuracy Dual CMOS Voltage Regulator

Rev. E19-01 VRD Series

BLOCK DIAGRAM

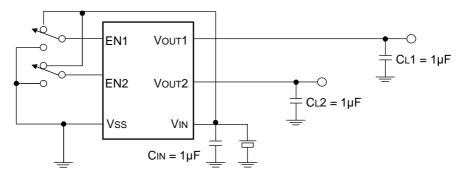


ABSOLUTE MAXIMUM RATINGS

Items		Symbol	Ratings	Unit
Input voltage range		VIN	− 0.3 ~ + 7.0	V
Output current		IOUT	500	mA
Output voltage range	Output voltage range		Vss -0.3 ~ VIN +0.3	V
	SOT-26	PD	600	mW
Power dissipation %1)	LLP-6	PD	1000	mW
	SON-6	PD	1000	mW
Operating temperature range		Topr	-40 ~ +85	°C
Storage temperature rar	Storage temperature range		−55 ~ + 125	°C

Note:

TYPICAL APPLICATION CIRCUITS



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^{*1)} Power dissipation depends on conditions of mounting on boards. PCB dimension is 50mm×50mm×1.6mm.

ELECTRICAL CHARACTERISTICS

(Ta=25°C unless otherwise specified)

Items	Symbol	Co	nditions	5	Min.	Тур.	Max.	Unit	Test circuit
Output voltage	Vоит	Vout+1.0V≦Vin≦ Iout=30mA	€6.0V	6.0V VOUT≧1.95V		Vout	Vоит × 1.01	V	1
Output voltage	V001	Ta=-40°C ~ +85°C		Vouт≦1.90V	-20	-	+20	mV	'
			0.9V	≦Vo∪т≦1.15V	-	250	-	mA	
			1.2V	≦Vouт≦1.65V	-	250	-	mA	
			1.7V	≦Vouт≦2.25V	-	250	-	mA	
Output current	Іоит	VIN≧VOUT+1.0V	2.3V	2.3V≦Vouт≦2.85V		250	-	mA	1
			2.9V≦VouT≦3.45V		-	250	-	mA	
			3.5V	3.5V≦Vouт≦4.05V		250	-	mA	
			4.0V	≦Vouт≦5.00V	-	250	-	mA	
		IOUT=100mA	0.9V	≦Vouт≦1.15V	-	580	910	mV	
			1.2V≦VouT≦1.65V		-	210	340	mV	
			1.7V	≦Vouт≦2.25V	-	130	205	mV	
Dropout voltage	VDROP		2.3V	≦Vouт≦2.85V	-	100	150	mV	1
			2.9V	≦Vouт≦3.45V	-	90	137	mV	
			3.5V	≦Vouт≦4.05V	-	85	125	mV	
			4.1V	≦Vouт≦5.00V	-	80	115	mV	

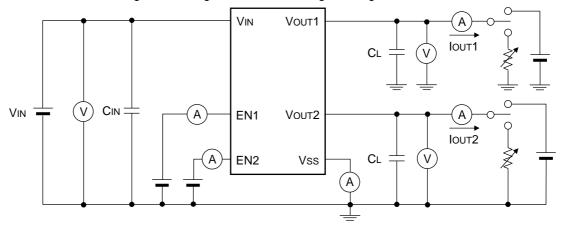
ELECTRICAL CHARACTERISTICS (CONTINUED)

(Ta=25°C unless otherwise specified)

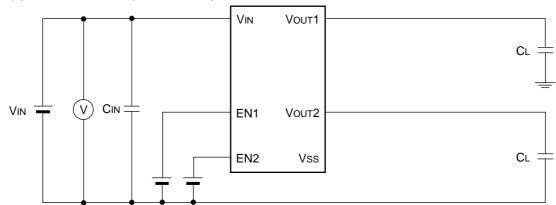
Items	Symbol	Conditions	Min.	Тур.	Max.	Unit	Test circuit
Current consumption	loo	VIN=Vout+1.0V, Vout=Open, Iout=0mA		50	80	μΑ	2
Standby current	ISTB	EN=Vss	-	0.01	0.1	μΑ	2
Input voltage	VIN		1.6	-	6.0	V	1
Load regulation	ΔVουτ	VIN=VOUT+1.0V, IOUT=0.1mA ~100mA	-	10	40	mV	1
Line regulation	ΔVout / ΔVin•Vout	Vout+1.0V≦VIN≦6.0V, Iout=30mA	-	0.01	0.1	%/V	1
Ripple rejection	Rr	VIN=VOUT+1.0V, f=1KHz, ΔVRIP=0.5VP-P, IOUT=30mA	-	75	-	dB	3
Limit current	Ішміт	EN=Vin	300	-	-	mA	1
Short circuit current	ISHORT	VIN=VOUT+1.0V, VOUT=0V	-	40	-	mA	1
Output voltage temperature coefficient	ΔVout / ΔTa•Vout	VEN=VIN, IOUT=300mA Ta=-40°C ~ +85°C		±20		ppm /°C	1
EN high level voltage	VENH		1.2	-	6.0	V	1
EN low level voltage	VENL		-	-	0.3	V	1
EN high level current	lenh	VEN= VIN	-0.1	-	0.1	μΑ	1
EN low level current	IENL	VEN= VSS	-0.1	-	0.1	μΑ	1
CL auto-discharge resistance	RDIS	VIN=6.0V, VOUT=4.0V, VEN= VSS	-	160	-	Ω	1

TEST CIRCUITS

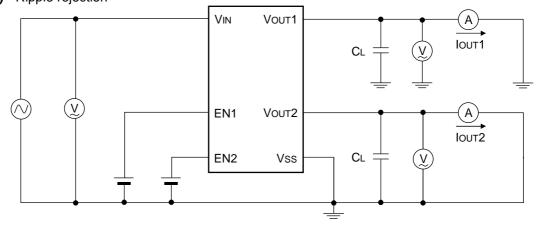
 Circuit (1) - Output voltage, Output current, Dropout voltage, Input voltage, Load regulation, Line regulation, Limit current, Short circuit current, Output voltage temperature coefficient, CL auto-discharge resistance, EN high level voltage, EN low level voltage, EN high level current, EN low level current



• Circuit (2) - Current consumption, Standby current



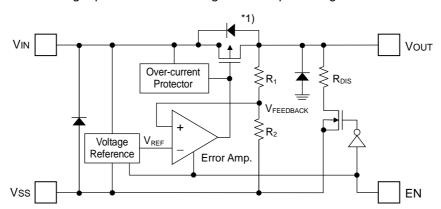
• Circuit (3) - Ripple rejection



DESCRIPTION OF OPERATION

General operation

In reference to following a part of the block diagram of output voltage control of the VRD series;



By the error amplifier, the reference voltage (V_{REF}) is compared with V_{FEEDBACK} which is divided by feedback resistors R₁ and R₂. It supplies the output transistor (see note *1) to keep a stabilized output voltage against with any fluctuation of input voltage by negative feedback system.

Note *1)

The VRD series has P-channel MOSFET which is connected to the VOUT terminal as the output transistor. To prevent the VRD series from being damaged due to inverse current from VOUT terminal to VIN terminal through a parasitic diode, VOUT should not be exceeded VIN+0.3V.

EN terminal (shutdown function) & CL auto-discharge

The VRD series can be shutdown through EN terminal. The P-channel MOSFET is turned off and operation of all internal circuits stops to reduce the current consumption when the signal of EN terminal is set to the shutdown level. In shutdown mode, the VRD series enables the electric charge at the CL to be discharged via the auto-discharge resistance (R_{DIS} ; 160Ω), and the Vout terminal can be rapidly returned to the Vss level as a result.

Output capacitor (CL)

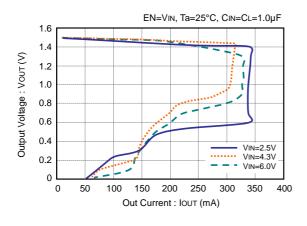
For phase compensation, an output capacitor (CL) is required to connected between Vout terminal and Vss terminal as close as possible. A ceramic capacitor with capacitance value of at least 1.0µF is recommended. Of course, the suitable capacitance value should be different by the condition of each application. In addition, an input capacitor (CIN) with capacitance value of at least 1.0µF is also recommended between VIN terminal and Vss terminal for stable input power.

Over current protection and short circuit protection

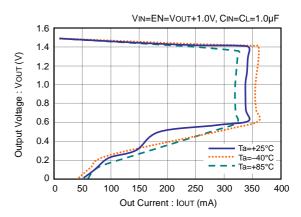
Built-in over current protection circuit performs circuit protection from over current as a current limiter. When the load current reaches the limit level, the output voltage drops and output current also decreases accordingly. A current of typ. 40mA will flow when output terminal is shorted.

TYPICAL CHARACTERISTICS - Output Voltage vs. Output Current

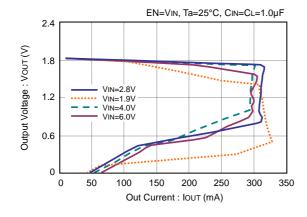
● VRD (Vout=1.5V)



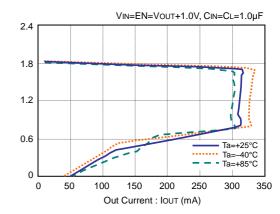
VRD (Vout=1.5V)



VRD (Vout=1.8V)

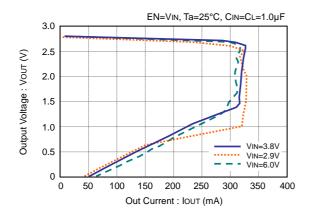


VRD (Vout=1.8V)

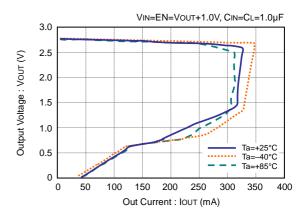


TYPICAL CHARACTERISTICS - Output Voltage vs. Output Current (continued)

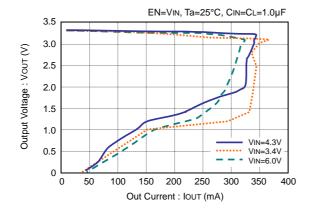
VRD (Vout=2.8V)



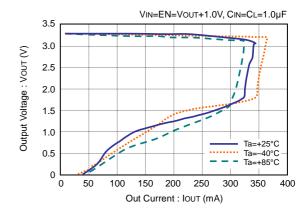
VRD (Vout=2.8V)



● VRD (Vout=3.3V)

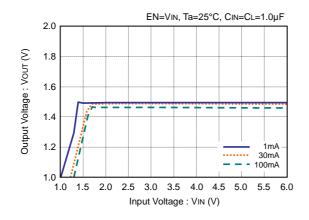


● VRD (Vout=3.3V)

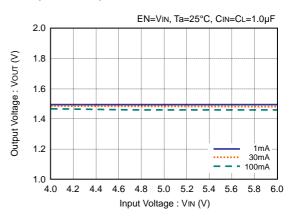


TYPICAL CHARACTERISTICS - Output Voltage vs. Input Voltage

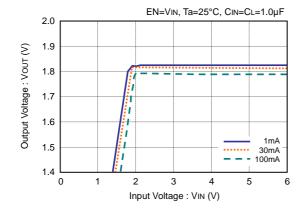
VRD (Vouт=1.5V)



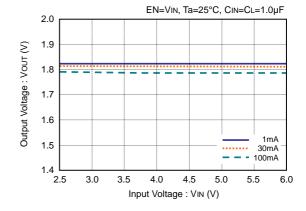
● VRD (Vout=1.5)



● VRD (Vout=1.8V)

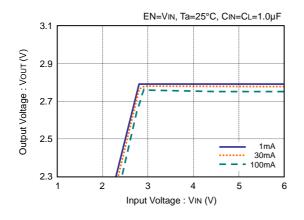


● VRD (Vout=1.8V)

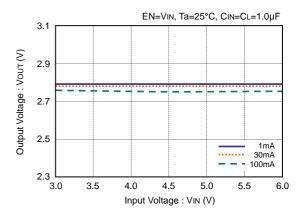


TYPICAL CHARACTERISTICS - Output Voltage vs. Input Voltage (continued)

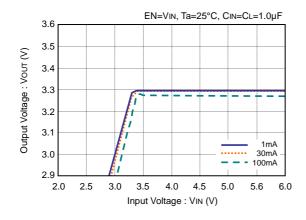
VRD (Vout=2.8V)



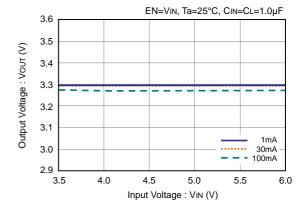
VRD (Vout=2.8V)



VRD (Vout=3.3V)

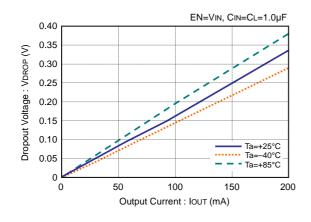


● VRD (Vout=3.3V)

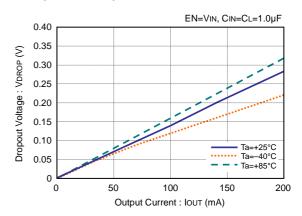


TYPICAL CHARACTERISTICS – Dropout Voltage vs. Output Current

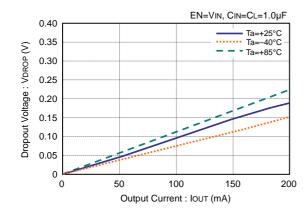
● VRD (Vout=1.5V)



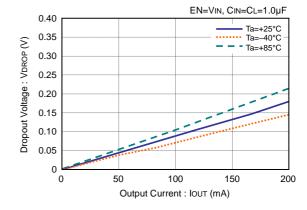
VRD (Vouт=1.8V)



● VRD (Vout=2.8V)

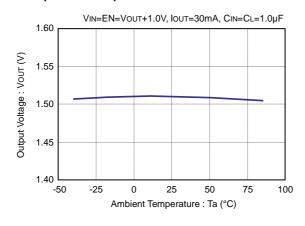


VRD (Vout=3.3V)

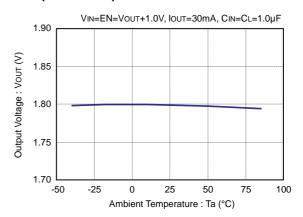


TYPICAL CHARACTERISTICS - Output Voltage vs. Ambient Temperature

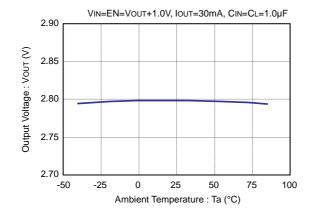
VRD (Vout=1.5V)



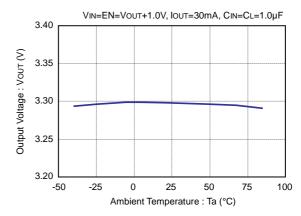
● VRD (Vout=1.8V)



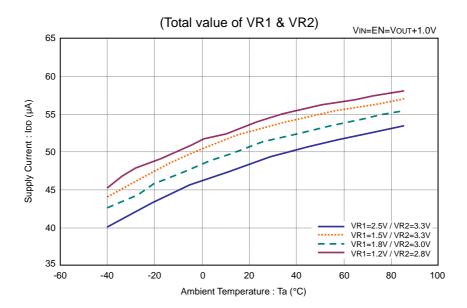
● VRD (Vout=2.8V)



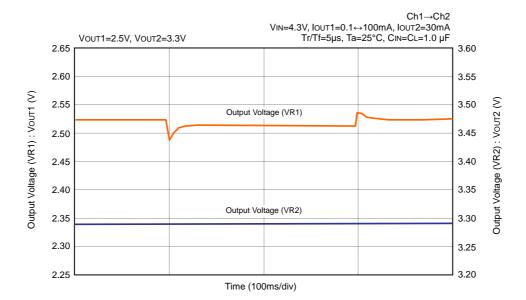
● VRD (Vout=3.3V)



TYPICAL CHARACTERISTICS – Supply Current vs. Ambient Temperature

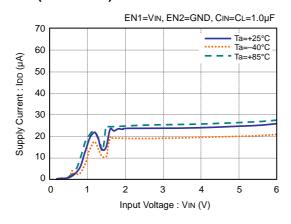


TYPICAL CHARACTERISTICS - Cross Talk

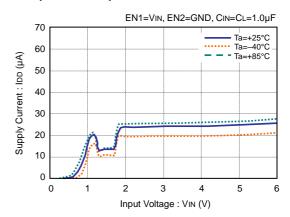


TYPICAL CHARACTERISTICS - Supply Current vs. Input Voltage

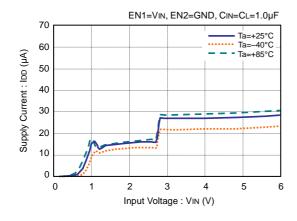
● VRD (Vout=1.5V)



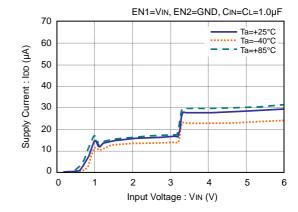
VRD (Vout=1.8V)



● VRD (Vout=2.8V)

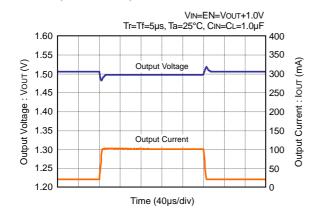


VRD (Vout=3.3V)

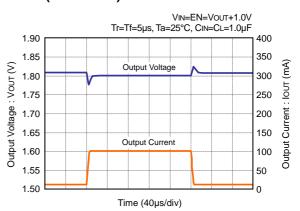


TYPICAL CHARACTERISTICS – Load Transient Response

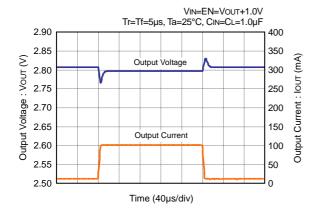
VRD (Vouт=1.5V)



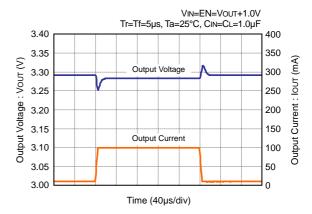
VRD (Vouт=1.8V)



VRD (Vout=2.8V)

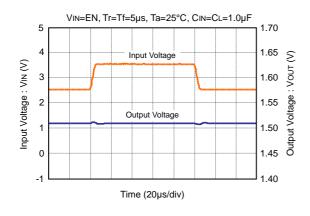


VRD (Vout=3.3V)

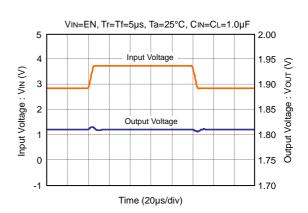


TYPICAL CHARACTERISTICS – Input Transient Response (lout=1mA)

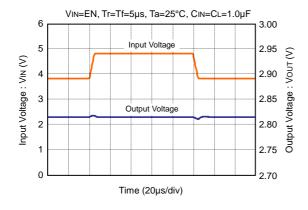
● VRD (Vout=1.5V)



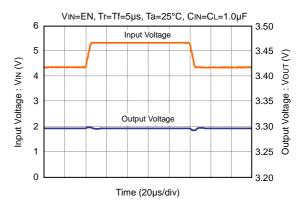
VRD (Vout=1.8V)



● VRD (Vout=2.8V)

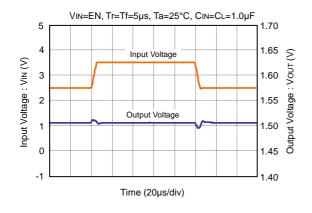


● VRD (Vout=3.3V)

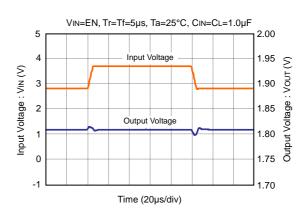


TYPICAL CHARACTERISTICS - Input Transient Response (lout=30mA)

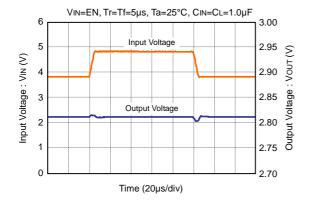
● VRD (Vout=1.5V)



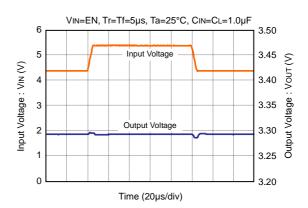
VRD (Vout=1.8V)



VRD (Vout=2.8V)

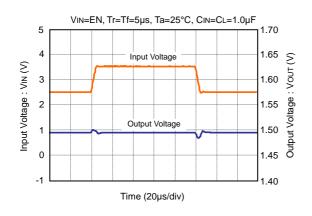


VRD (Vout=3.3V)

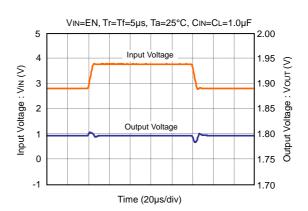


TYPICAL CHARACTERISTICS - Input Transient Response (Iout=100mA)

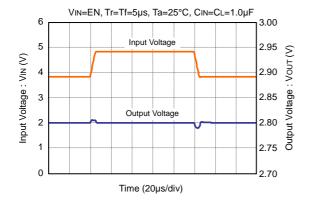
● VRD (Vout=1.5V)



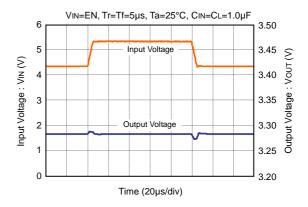
VRD (Vout=1.8V)



VRD (Vout=2.8V)

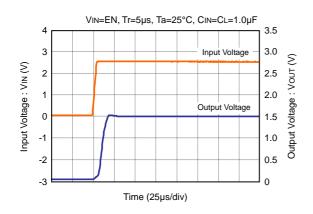


VRD (Vout=3.3V)

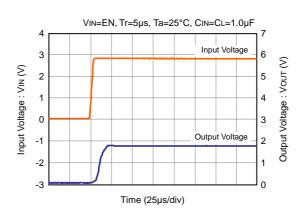


TYPICAL CHARACTERISTICS – Input Rise Time (Iout=1mA)

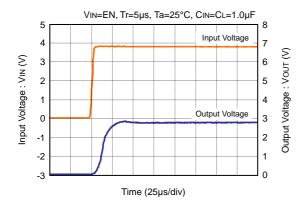
● VRD (Vout=1.5V)



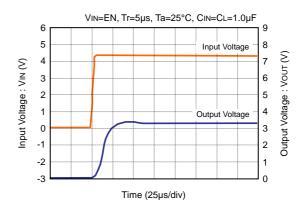
VRD (Vouт=1.8V)



● VRD (Vout=2.8V)

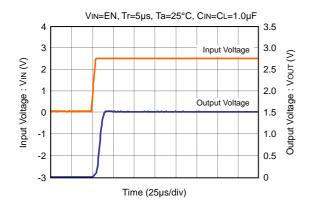


VRD (Vout=3.3V)

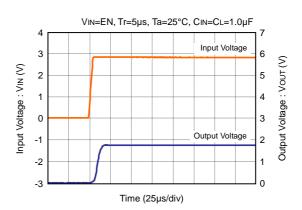


TYPICAL CHARACTERISTICS – Input Rise Time (Iout=30mA)

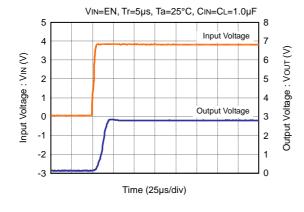
● VRD (Vout=1.5V)



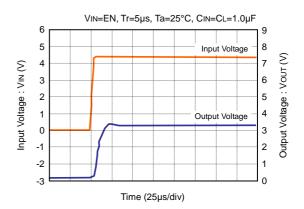
● VRD (Vout=1.8V)



● VRD (Vout=2.8V)

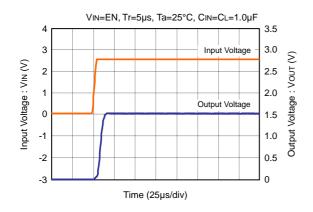


VRD (Vout=3.3V)

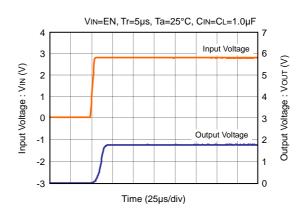


TYPICAL CHARACTERISTICS – Input Rise Time (Iout=100mA)

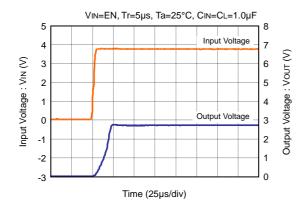
● VRD (Vout=1.5V)



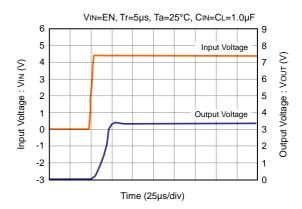
VRD (Vout=1.8V)



● VRD (Vout=2.8V)

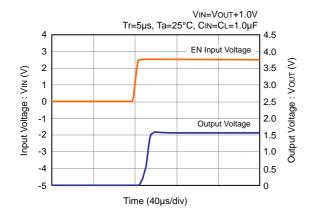


VRD (Vout=3.3V)

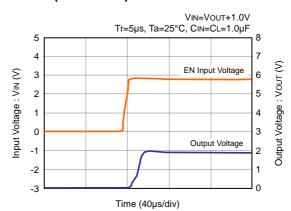


TYPICAL CHARACTERISTICS – EN Rise Time (lout=1mA)

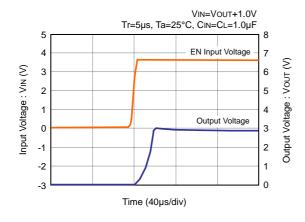
● VRD (Vout=1.5V)



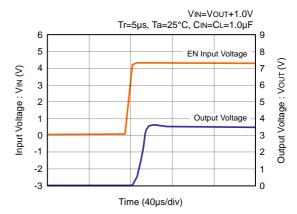
VRD (Vout=1.8V)



VRD (Vout=2.8V)

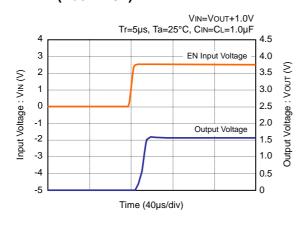


VRD (Vout=3.3V)

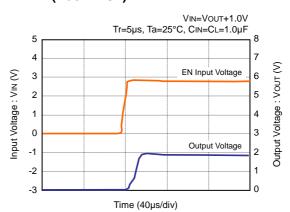


TYPICAL CHARACTERISTICS - EN Rise Time (lout=30mA)

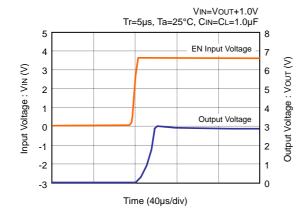
● VRD (Vout=1.5V)



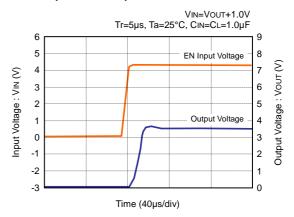
● VRD (Vout=1.8V)



● VRD (Vout=2.8V)

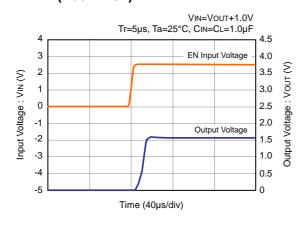


● VRD (Vout=3.3V)

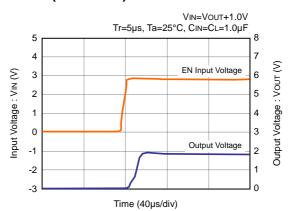


TYPICAL CHARACTERISTICS – EN Rise Time (lout=100mA)

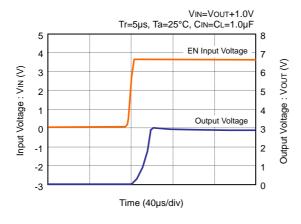
● VRD (Vout=1.5V)



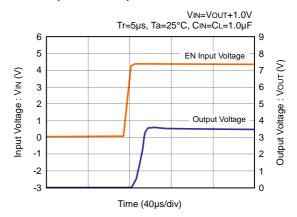
● VRD (Vout=1.8V)



VRD (Vout=2.8V)

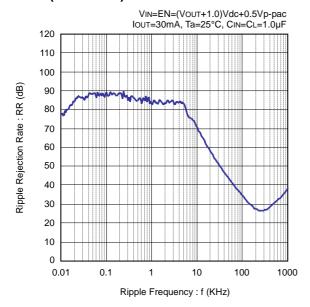


VRD (Vout=3.3V)

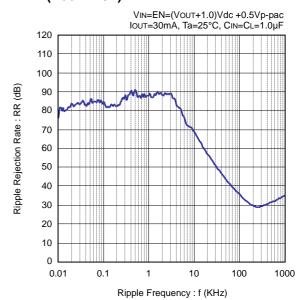


TYPICAL CHARACTERISTICS - Ripple Rejection Rate

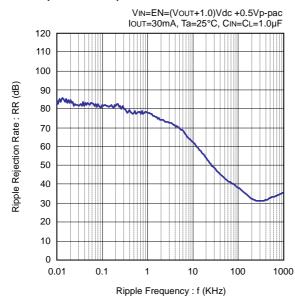
● VRD (Vout=1.5V)



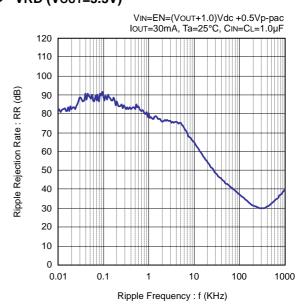
VRD (Vout=1.8V)



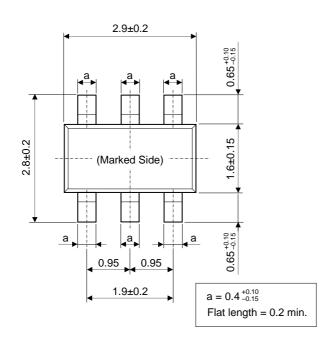
VRD (Vout=2.8V)

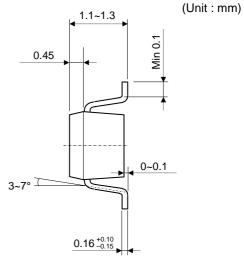


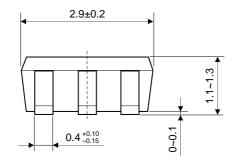
● VRD (Vout=3.3V)

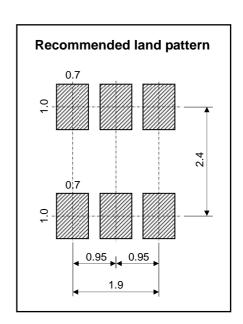


PACKAGE DIMENSIONS (SOT-26)



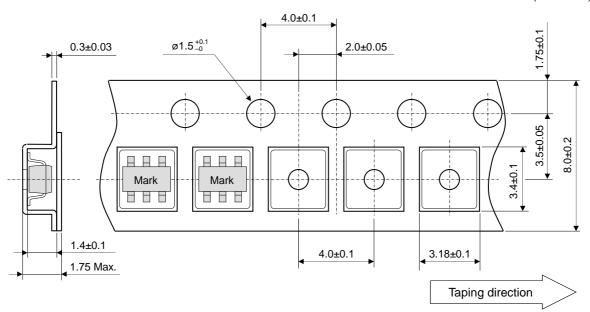






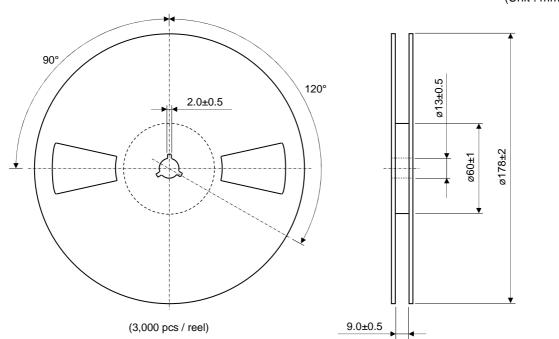
TAPING AND LOADING SPECIFICATIONS (SOT-26)

(Unit: mm)

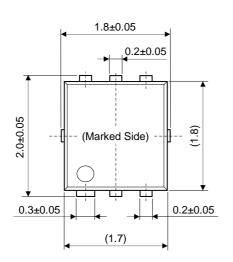


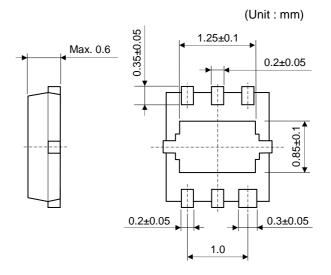
REEL DIMENSIONS (SOT-26)

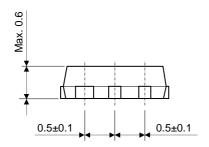
(Unit:mm)

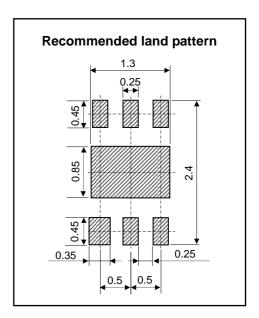


PACKAGE DIMENSIONS (SON-6)



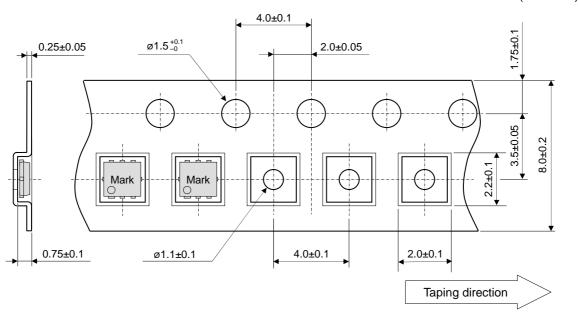






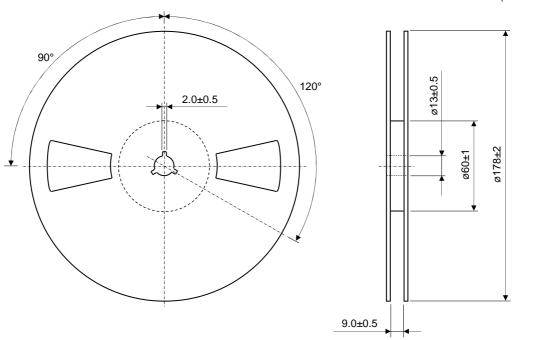
TAPING AND LOADING SPECIFICATIONS (SON-6)

(Unit:mm)



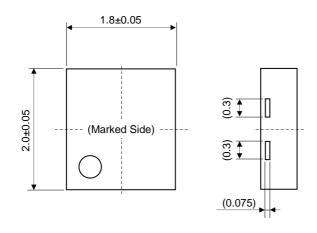
REEL DIMENSIONS (SON-6)

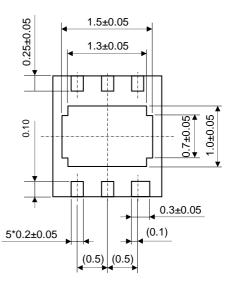
(Unit: mm)

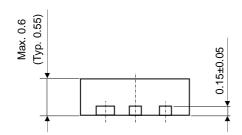


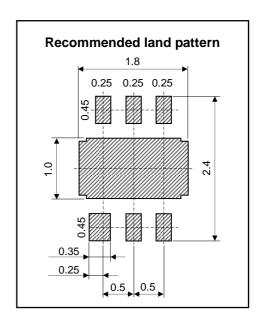
PACKAGE DIMENSIONS (LLP-6)

(Unit: mm)



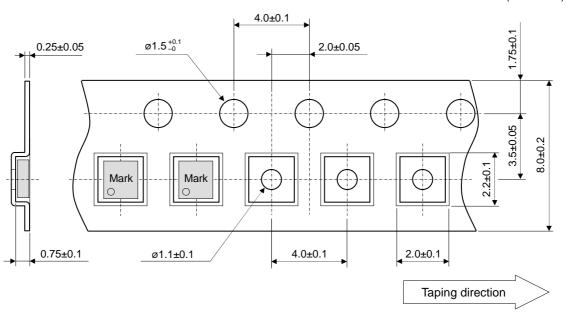






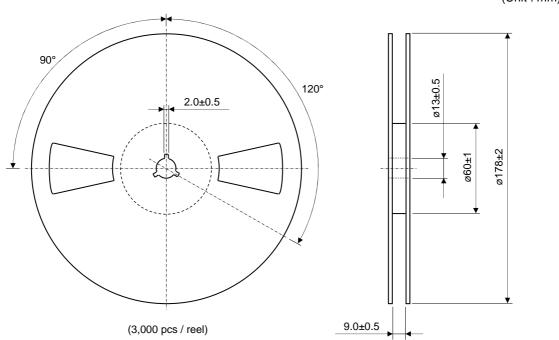
TAPING AND LOADING SPECIFICATIONS (LLP-6)

(Unit: mm)



REEL DIMENSIONS (LLP-6)

(Unit:mm)





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